This datasheet describes the use of the MiCS-2614 in ozone detection applications. The package and the mode of operation described in this document target the detection of the oxidising gas O_3 in indoor or outdoor environments. Ozone is a hazardous gas, which can cause respiratory problems at concentrations above 100 ppb.

FEATURES

- Low heater current
- Wide detection range
- High sensitivity
- Fast thermal response
- Miniature dimensions
- · High resistance to shocks and vibrations

IMPORTANT PRECAUTIONS

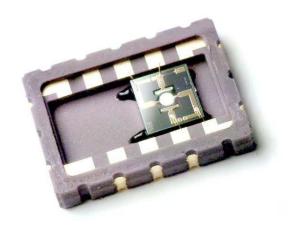
Read the following instructions carefully before using the MiCS-2614 sensor described in this document to avoid erroneous readings and to prevent the device from permanent damage.

- The sensor must not be wave soldered without protection, or exposed to high concentrations of organic solvents, ammonia, or silicone vapours, to avoid poisoning the sensitive layer.
- Heating powers above the maximum rating of 95 mW can destroy the sensor due to overheating.
- After exposing the sensor to high concentrations of O₃, make sure the sensor is given enough time to recover before taking new measurements.
- For any additional questions, email enquiries@e2v.com or telephone +44 (0)1245 493493.

OPERATING MODE

The recommended mode of operation is a constant voltage mode. A heater power of $P_{\rm H}$ = 80 mW is applied. This causes the temperature of the sensing resistor ($R_{\rm S}$) to reach about 430 °C.

Detection of the O_3 concentration is achieved by measuring the sensing resistor R_S during operation.



Product shown without cap

SENSOR CONFIGURATION

The silicon gas sensor structure consists of an accurately micro machined diaphragm with an embedded heating resistor and the sensing layer on top.

The internal connections are shown below.

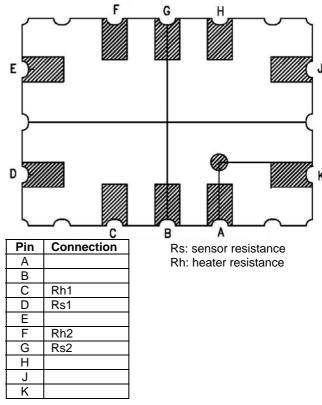


Fig. 1: MiCS-2614 configuration (bottom view).

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POWER CIRCUIT EXAMPLE

As shown below, one external load resistor can be used to power the heater with a single 5 V power supply.

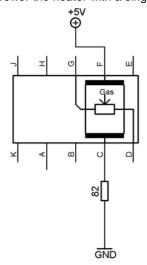


Figure 2: MiCS-2614 with recommended supply circuit (top view)

R is 82 Ω . This resistor is necessary to obtain the right temperature on the heater while using a single 5 V power supply. The resulting voltages is typically VH = 2.35 V.

SENSOR CHARACTERISTICS

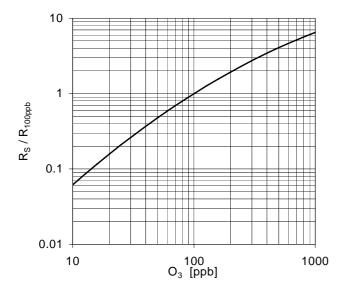


Fig. 4: R_s/R_0 as a function of gas concentration at 50% RH and 25 °C.

MEASUREMENT CIRCUIT EXAMPLE

As shown below, the sensitive resistance shall be read by using a load resistor.

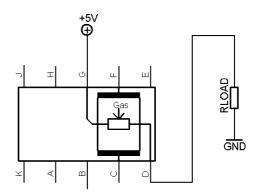


Figure 3: MiCS-2614 with measurement circuit (top view)

The voltage measured on the load resistor is directly linked to the resistance of the sensor. RLOAD must be 820 Ω at the lowest in order not to damage the sensitive layer.

ELECTRICAL CHARACTERISTICS

Rating	Symbol	Value/Range	Unit
Maximum heater power dissipation (see note 1)	P _H	95	mW
Maximum sensitive layer power dissipation	Ps	1	mW
Voltage supply	V_{supply}	4.9 – 5.1	V
Relative humidity range	R _H	5 – 95	%RH
Ambient operating temperature	T _{amb}	-40 – 70	°C
Storage temperature range (see note 2)	T _{sto}	-40 – 50	°C
Storage humidity range	RH _{sto}	5 - 95	%RH

OPERATING CONDITIONS

Parameter	Symbol	Тур	Min	Max	Unit
Heating power (see note 3)	Рн	80	66	95	mW
Heating voltage	V_{H}	2.35	-	-	V
Heating current	I _H	34	-	-	mA
Heating resistance at nominal power (see note 4)	R _H	68	58	78	Ω

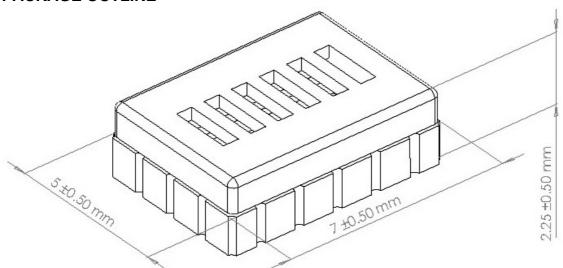
SENSITIVITY CHARACTERISTICS

Characteristic	Symbol	Тур	Min	Max	Unit
O ₃ detection range	FS		10	1000	ppm
Sensing resistance in air	R ₀	11	3	60	kΩ
Sensitivity factor (see note 5)	S _R	2	1.5	4	-

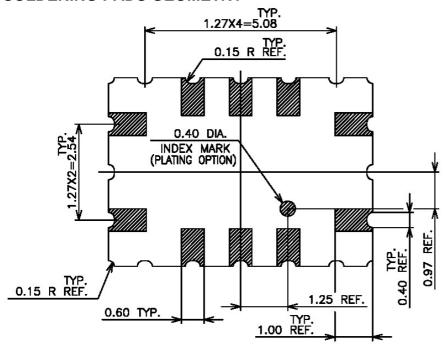
Notes:

- 1. Heating powers above 95 mW can cause permanent damage to the sensor due to overheating.
- 2. Storage of parts in original shipping package.
- 3. To ensure a correct operating temperature, the heater voltage should be ajusted so that the resulting heating power equals 80 mW. Lower heating power will reduce the sensitivity and increase the response time. Heating powers above 95 mW can cause permanent damage to the sensor due to overheating.
- 4. Heating resistor values from sensors out of production range between 58 and 78 Ω measured at V_H = 2.35V. Due to material properties of the heating resistor its value increases during operating life.
- 5. Sensitivity factor S_R is defined as R_s at 100 ppb of O_3 divided by R_s at 50 ppb of O_3 . Test conditions are 50 \pm 5% RH and 25 \pm 2 °C.

PACKAGE OUTLINE



SOLDERING PADS GEOMETRY



e2v semiconductor gas sensors are well suited for leak detection and applications requiring limited accuracy. Their use for absolute gas concentration detection is more complicated because they typically require temperature compensation, calibration, and sometimes as well, humidity compensation. Their base resistance in clean air and their sensitivity can vary overtime depending on the environment they are in. This effect must be taken into account for any application development (1087-1.1).